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2. **Van Loi Le**, J. Li, A. Chang, and Tony T. Kim, "A 0.4-V 0.138-fJ/Cycle Single-Phase-Clocking Redundant-Transition-Free 24T Flip-Flop with Change-Sensing Scheme in 40-nm CMOS," *IEEE Journal of Solid-State Circuits (JSSC)*, vol. 53, Aug. 2018.

3. **Van Loi Le** and Tony T. Kim, "An Area and Energy Efficient Ultra-Low Voltage Level Shifter with Pass Transistor and Reduced-Swing Output Buffer in 65-nm CMOS," *IEEE Transactions on Circuits and Systems-II (TCAS-II)*, Vol. 65, pp. 607-611, May 2018.

4. **Van Loi Le***, T. Yoo*, J. E. Kim, N. L. Ba, K.-H. Baek, Tony T. Kim, "A 137-µW 1.78mm^2 30-frames/s Real-Time Gesture Recognition System for Smart Devices", *IEEE Journal of Solid-State Circuits (JSSC),* to be submitted for review. (*Equally contributed)

5. **Van Loi Le***, T. Yoo*, J. E. Kim, K.-H. Baek, Tony T. Kim, "A 213.7-µW 0.54mm^2 Real-Time Gesture Recognition System in 65nm for Smart Wearable Devices", *2019 IEEE International Solid-State Circuit Conference (ISSCC),* submitted. (*Equally contributed)

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